

DESCRIPTION

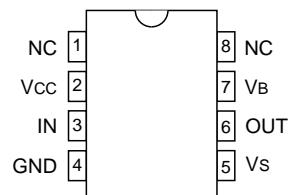
M81705FP is high voltage Power MOSFET and IGBT module driver for half bridge applications.

FEATURES

- FLOWING SUPPLY VOLTAGE 600V
- OUTPUT CURRENT +150mA
-125mA
- HIGH SIDE DRIVER
- SOP-8

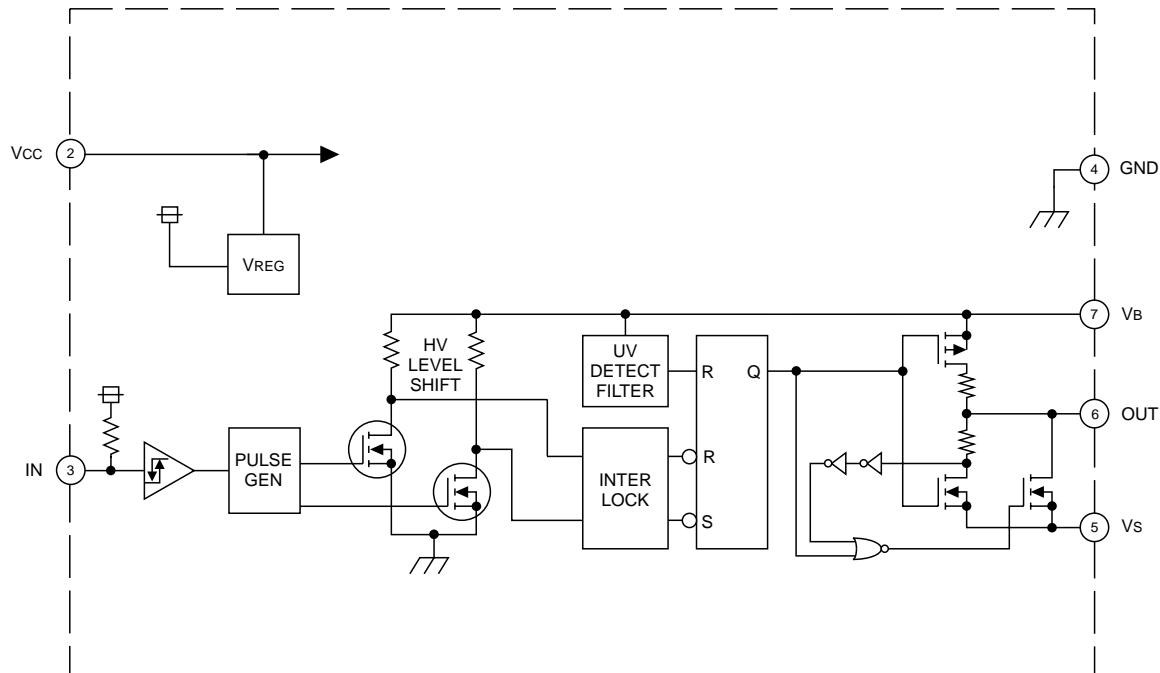
APPLICATIONS

PDP, MOSFET and IGBT module inverter driver for AC-servomotor and general purpose.

PIN CONFIGURATION (TOP VIEW)

NC: NO INTERNAL CONNECTION

Outline 8P2S

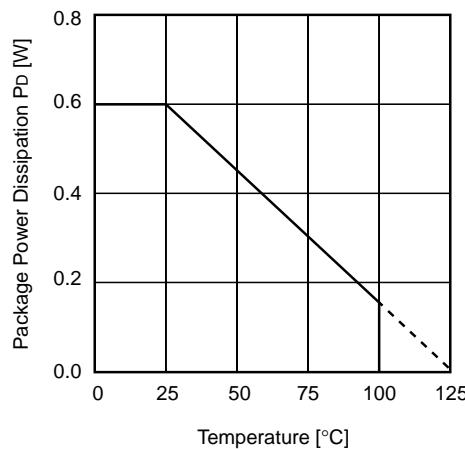
BLOCK DIAGRAM

HIGH VOLTAGE HIGH SIDE DRIVER**ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Conditions	Ratings	Unit
V _B	High Side Floating Supply Absolute Voltage		-0.5 ~ 624	V
V _S	High Side Floating Supply Offset Voltage		V _B -24 ~ V _B +0.5	V
V _{BS}	High Side Floating Supply Voltage	V _{BS} = V _B -V _S	-0.5 ~ 24	V
V _{OUT}	High Side Output Voltage		V _S -0.5 ~ V _B +0.5	V
V _{CC}	Low Side Fixed Supply Voltage		-0.5 ~ 24	V
V _{IN}	Logic Input Voltage		-0.5 ~ 5.5	V
dV _S /dt	Allowable Offset Supply Voltage Transient		±50	V/ns
P _D	Package Power Dissipation	T _a = 25°C, On Board	0.60	W
K _θ	Linear Derating Factor	T _a > 25°C, On Board	-6.0	mW/°C
R _{th(j-c)}	Junction-Case Thermal Resistance		50	°C/W
T _j	Junction Temperature		-20 ~ 125	°C
T _{opr}	Operation Temperature		-20 ~ 100	°C
T _{stg}	Storage Temperature		-40 ~ 125	°C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V _B	High Side Floating Supply Absolute Voltage		V _S +13.5	—	V _S +20	V
V _S	High Side Floating Supply Offset Voltage	V _B > 13.5V	-5	—	500	V
V _{BS}	High Side Floating Supply Voltage	V _{BS} = V _B -V _S	13.5	—	20	V
V _{CC}	Low Side Fixed Supply Voltage		13.5	—	20	V
V _{IN}	Logic Input Voltage		0	—	5	V

THERMAL DERATING FACTOR CHARACTERISTIC

HIGH VOLTAGE HIGH SIDE DRIVER**ELECTRICAL CHARACTERISTICS (Ta=25°C, Vcc=Vbs (=Vb-Vs)=15V, unless otherwise specified)**

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.*	Max.	
I _{FS}	Floating Supply Leakage Current	V _B =V _S =600V	—	—	1.0	μA
I _{BS}	V _{BS} Standby Current		0.25	0.50	0.75	mA
I _{CC}	V _{CC} Standby Current		0.50	0.75	1.00	mA
V _{OH}	High Level Output Voltage	I _O =0A	14.9	—	—	V
V _{OL}	Low Level Output Voltage	I _O =0A	—	—	0.1	V
V _{IH}	High Level Input Threshold Voltage		2.5	3.0	4.0	V
V _{IL}	Low Level Input Threshold Voltage		0.8	1.5	2.0	V
I _{IH}	High Level Input Bias Current	V _{IN} =5V	-50	-20	—	μA
I _{IL}	Low Level Input Bias Current	V _{IN} =0V	-200	-100	—	μA
V _{BSuvr}	V _{BS} Supply UV Reset Voltage		10.5	11.5	12.5	V
V _{BSuvh}	V _{BS} Supply UV Hysteresis Voltage		0.2	0.5	0.8	V
t _{VBSSuv}	V _{BS} Supply UV Filter Time		—	5	—	μs
I _{OH}	Output High Level Short Circuit Pulsed Current	V _O =0V, V _{IN} =0V, PW<10μs	—	-125	—	mA
I _{OL1}	Output Low Level Short Circuit Pulsed Current	V _O =1V, V _{IN} =5V, PW<10μs	—	40	—	mA
I _{OL2}	Output Low Level Short Circuit Pulsed Current	V _O =15V, V _{IN} =5V, PW<10μs	—	150	—	mA
R _{OH}	Output High Level On Resistance	I _O =-100mA, R _{OH} =(V _{OH} -V _O)/I _O	—	120	160	Ω
R _{OL1}	Output Low Level On Resistance1	V _O =1V, R _{OL1} =V _O /I _O	—	50	60	Ω
R _{OL2}	Output Low Level On Resistance2	V _O =5V, R _{OL2} =V _O /I _O	—	100	130	Ω
t _{dLH}	High Side Turn-On Propagation Delay	CL=1000pF between OUT – V _S	100	—	500	ns
t _{dHL}	High Side Turn-Off Propagation Delay	CL=1000pF between OUT – V _S	100	—	500	ns
t _r	High Side Turn-On Rise Time	CL=1000pF between OUT – V _S	—	220	—	ns
t _f	High Side Turn-Off Fall Time	CL=1000pF between OUT – V _S	—	110	—	ns
V _{Oth}	R _{OL1} /R _{OL2} Switching Output Voltage		1.5	2.5	4.0	V

* Typ. is not specified.

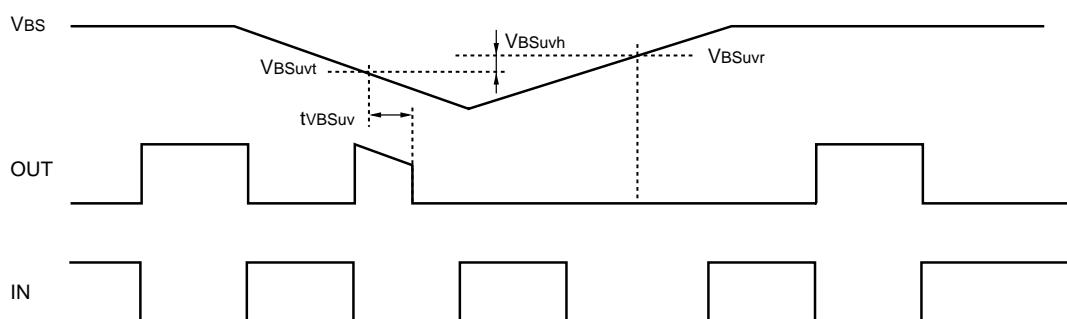
HIGH VOLTAGE HIGH SIDE DRIVER**TIMING DIAGRAM**

1. Input/Output Timing Diagram

When input signal is "L", then output signal "H".

2. VBS Supply Under Voltage Lockout Timing Diagram

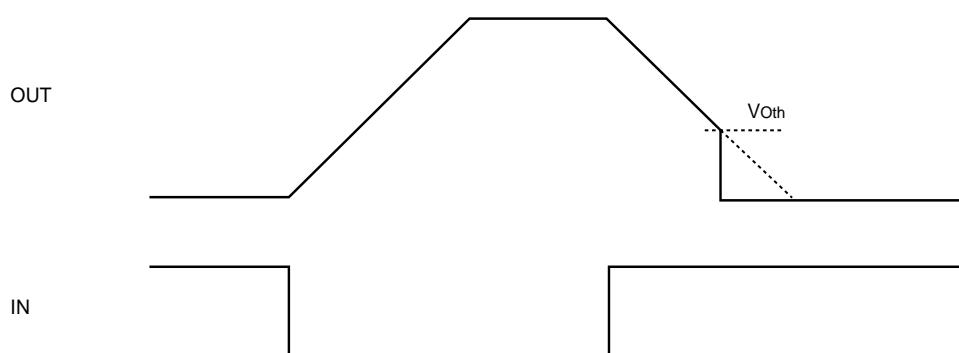
When VBS Supply Voltage keeps lower UV Trip Voltage ($VBS_{UVT} = VBS_{UVr} - VBS_{UVh}$) for VBS Supply UV Filter Time, output signal becomes "L". And then, VBS Supply Voltage is higher UV Reset Voltage, output signal keeps "L" until next input signal is "L".



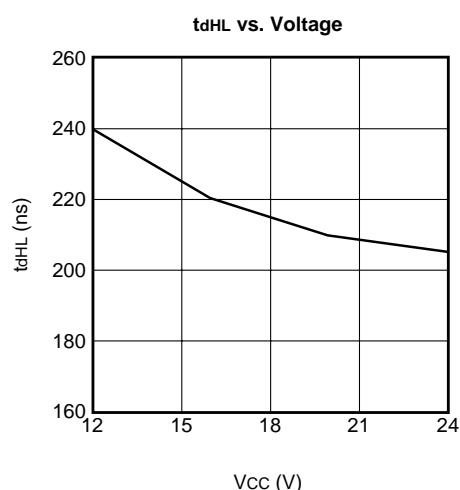
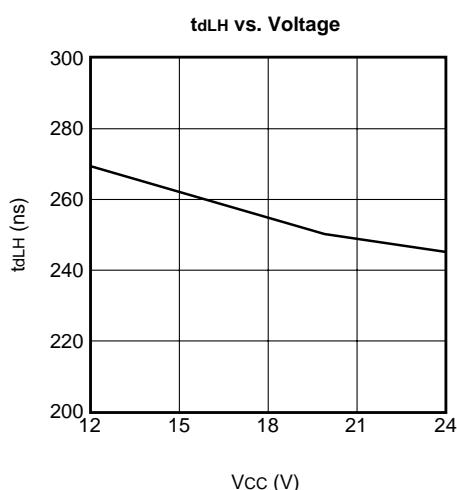
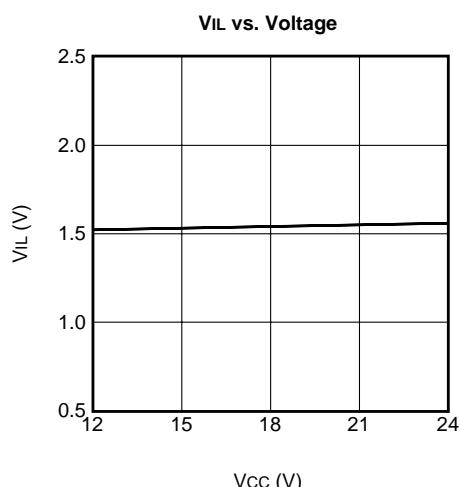
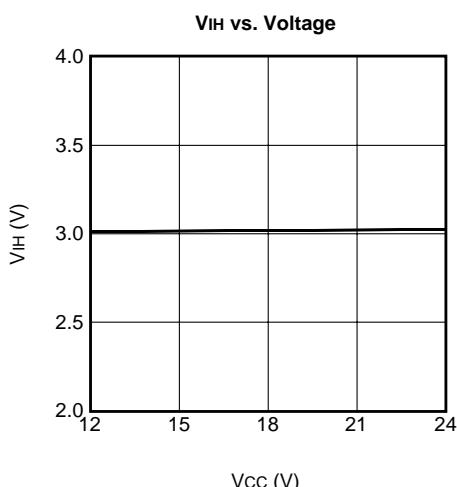
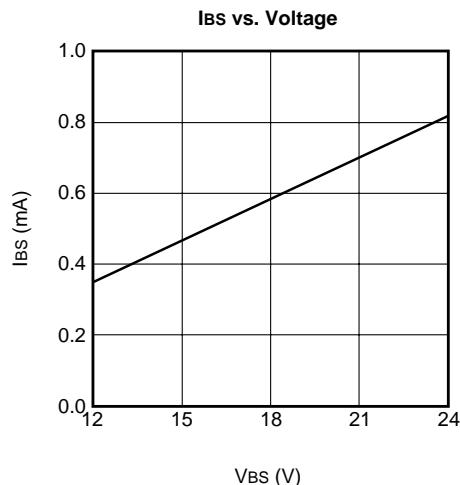
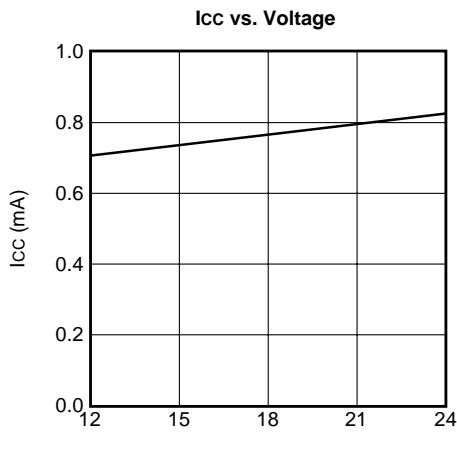
3. Allowable supply voltage transient

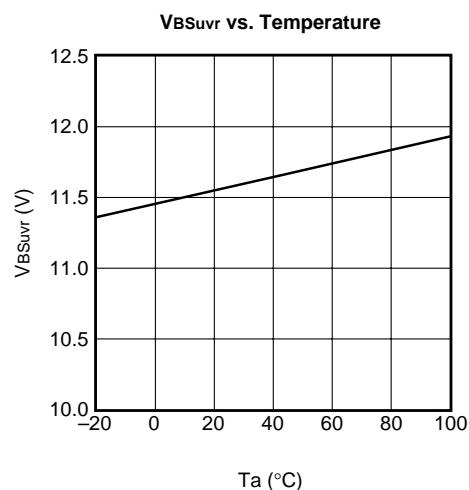
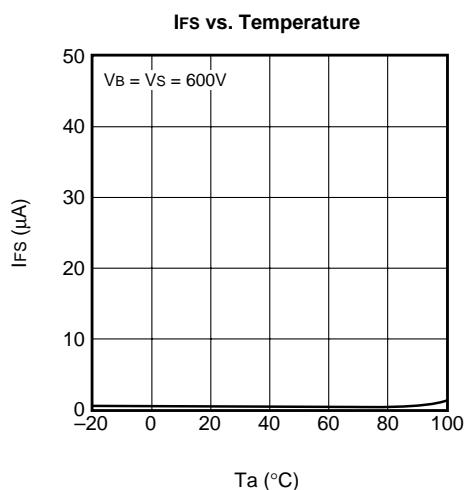
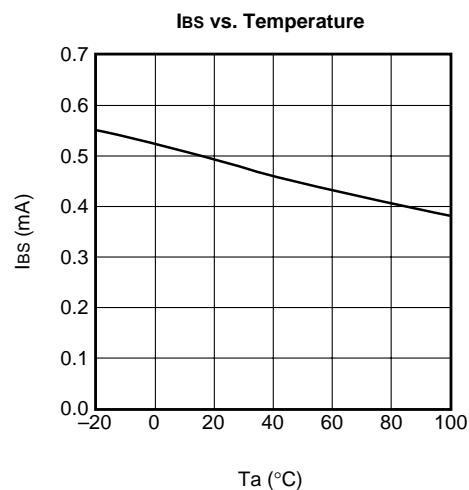
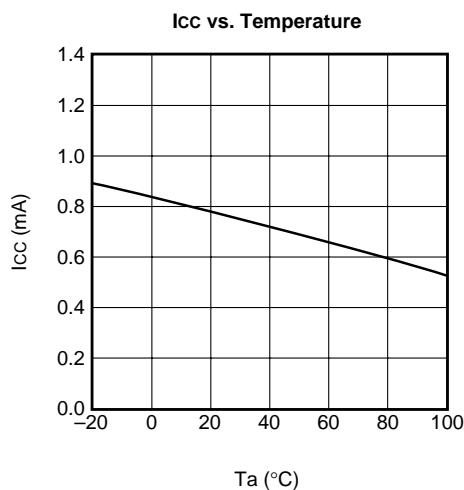
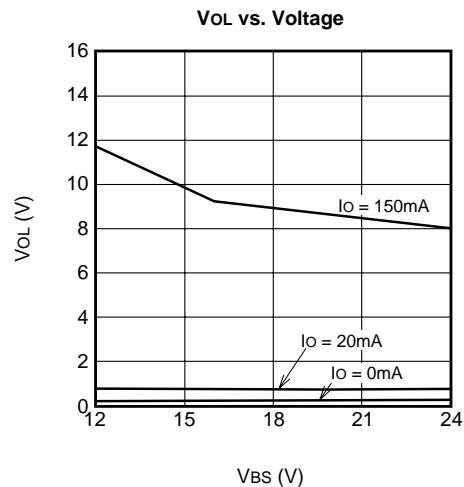
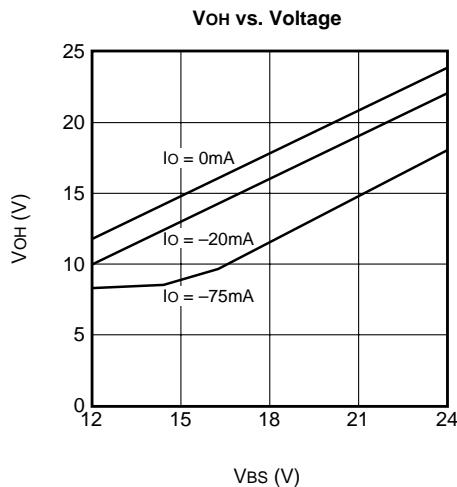
Firstly, supply Vcc with voltage. Secondly, supply Vbs with voltage. In the case of shutting off supply voltage, shut off Vbs Supply Voltage firstly. Secondly, shut off Vcc Supply Voltage.

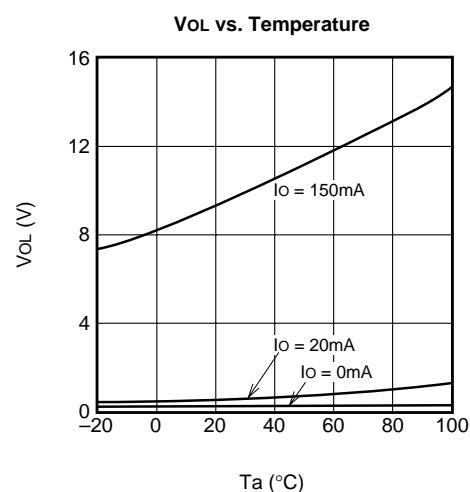
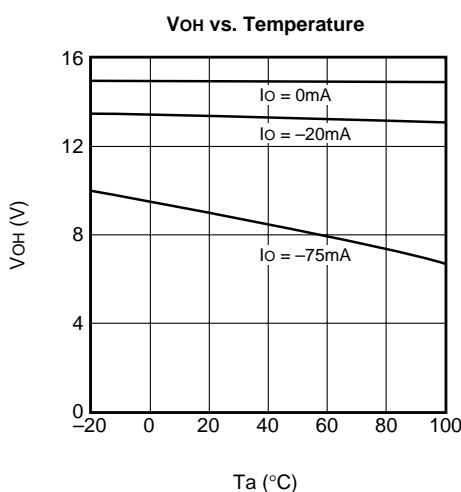
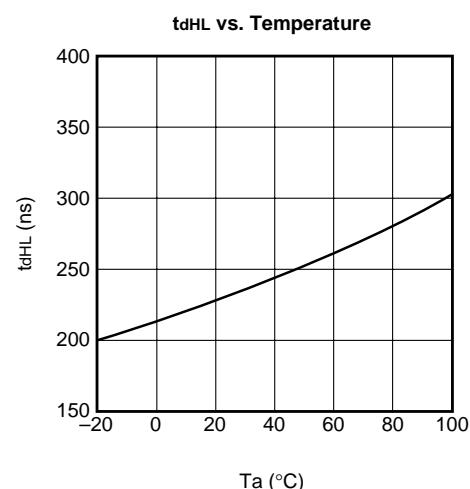
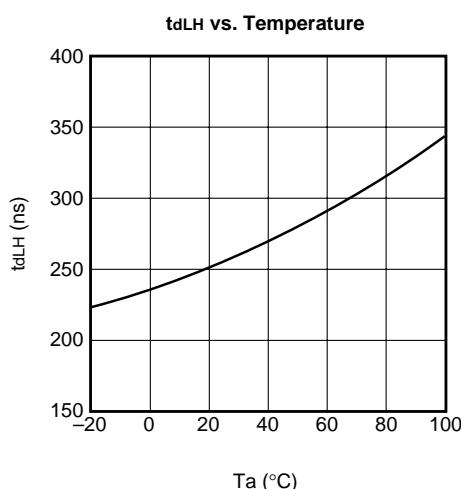
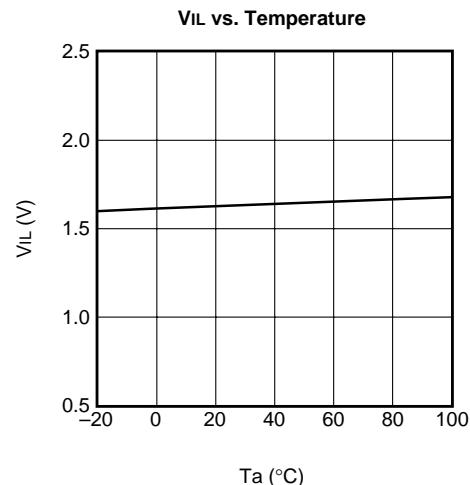
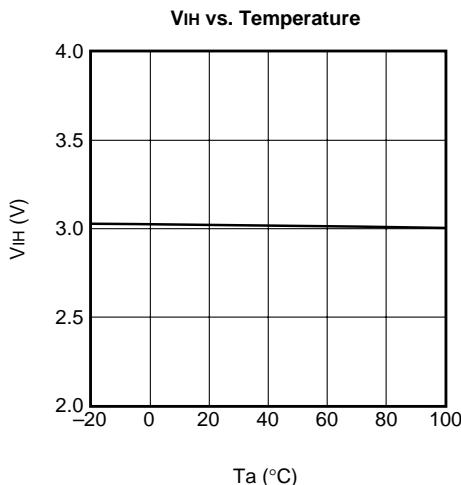
In case Vbs or Vcc is started too fast, output signal may be "H".

4. ROL1/ROL2 Switching Output Voltage V_{Oth} 

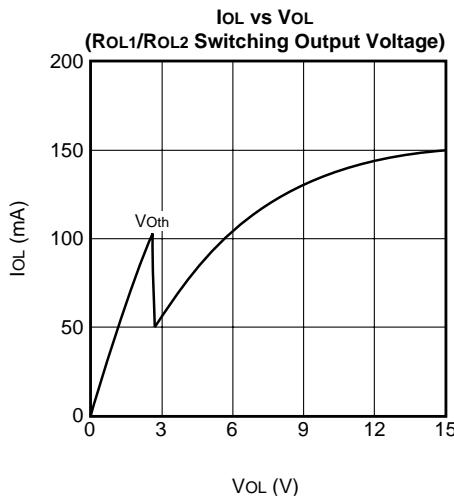
As shown by the solid line of the timing chart, the output on-resistance drops at ' V_{Oth} ' level when the output is in the 'L' state (output level falls). Below the ' V_{Oth} ' level, the output level falls more steeply.

HIGH VOLTAGE HIGH SIDE DRIVER**PERFORMANCE CURVES**

HIGH VOLTAGE HIGH SIDE DRIVER

HIGH VOLTAGE HIGH SIDE DRIVER

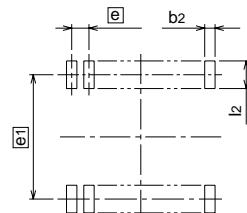
HIGH VOLTAGE HIGH SIDE DRIVER



PACKAGE OUTLINE

8P2S-A

EIAJ Package Code	JEDEC Code	Weight(g)	Lead Material
SOP8-P-225-1.27	-	0.07	Cu Alloy

Plastic 8pin 225mil SOP

Recommended Mount Pad

Symbol	Dimension in Millimeters		
	Min	Nom	Max
A	—	—	1.9
A ₁	0.05	—	—
A ₂	—	1.5	—
b	0.35	0.4	0.5
c	0.13	0.15	0.2
D	4.8	5.0	5.2
E	4.2	4.4	4.6
[e]	—	1.27	—
H _E	5.9	6.2	6.5
L	0.2	0.4	0.6
L ₁	—	0.9	—
[Z]	—	0.595	—
Z ₁	—	—	0.745
x	—	—	0.25
y	—	—	0.1
θ	0°	—	10°
b ₂	—	0.76	—
[e ₁]	—	5.72	—
l ₂	1.27	—	—

